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#### Understanding <u>Embedded - FPGAs (Field</u> <u>Programmable Gate Array)</u>

Embedded - FPGAs, or Field Programmable Gate Arrays, are advanced integrated circuits that offer unparalleled flexibility and performance for digital systems. Unlike traditional fixed-function logic devices, FPGAs can be programmed and reprogrammed to execute a wide array of logical operations, enabling customized functionality tailored to specific applications. This reprogrammability allows developers to iterate designs quickly and implement complex functions without the need for custom hardware.

#### **Applications of Embedded - FPGAs**

The versatility of Embedded - FPGAs makes them indispensable in numerous fields. In telecommunications.

#### Details

Product Status	Obsolete
Number of LABs/CLBs	-
Number of Logic Elements/Cells	-
Total RAM Bits	110592
Number of I/O	95
Number of Gates	600000
Voltage - Supply	1.425V ~ 1.575V
Mounting Type	Surface Mount
Operating Temperature	-40°C ~ 100°C (TJ)
Package / Case	208-BFQFP
Supplier Device Package	208-PQFP (28x28)
Purchase URL	https://www.e-xfl.com/product-detail/microsemi/m1afs600-1pqg208i

Email: info@E-XFL.COM

Address: Room A, 16/F, Full Win Commercial Centre, 573 Nathan Road, Mongkok, Hong Kong

The on-chip crystal and RC oscillators work in conjunction with the integrated phase-locked loops (PLLs) to provide clocking support to the FPGA array and on-chip resources. In addition to supporting typical RTC uses such as watchdog timer, the Fusion RTC can control the on-chip voltage regulator to power down the device (FPGA fabric, flash memory block, and ADC), enabling a low power standby mode.

The Fusion family offers revolutionary features, never before available in an FPGA. The nonvolatile flash technology gives the Fusion solution the advantage of being a highly secure, low power, single-chip solution that is Instant On. Fusion is reprogrammable and offers time-to-market benefits at an ASIC-level unit cost. These features enable designers to create high-density systems using existing ASIC or FPGA design flows and tools.

# Flash Advantages

# Reduced Cost of Ownership

Advantages to the designer extend beyond low unit cost, high performance, and ease of use. Flashbased Fusion devices are Instant On and do not need to be loaded from an external boot PROM.

On-board security mechanisms prevent access to the programming information and enable remote updates of the FPGA logic that are protected with high level security. Designers can perform remote insystem reprogramming to support future design iterations and field upgrades, with confidence that valuable IP is highly unlikely to be compromised or copied. ISP can be performed using the

industry-standard AES algorithm with MAC data authentication on the device. The Fusion family device architecture mitigates the need for ASIC migration at higher user volumes. This makes the Fusion family a cost-effective ASIC replacement solution for applications in the consumer, networking and communications, computing, and avionics markets.

# Security

As the nonvolatile, flash-based Fusion family requires no boot PROM, there is no vulnerable external bitstream. Fusion devices incorporate FlashLock, which provides a unique combination of reprogrammability and design security without external overhead, advantages that only an FPGA with nonvolatile flash programming can offer.

Fusion devices utilize a 128-bit flash-based key lock and a separate AES key to provide the highest level of protection in the FPGA industry for programmed IP and configuration data. The FlashROM data in Fusion devices can also be encrypted prior to loading. Additionally, the flash memory blocks can be programmed during runtime using the industry-leading AES-128 block cipher encryption standard (FIPS Publication 192). The AES standard was adopted by the National Institute of Standards and Technology (NIST) in 2000 and replaces the DES standard, which was adopted in 1977. Fusion devices have a

built-in AES decryption engine and a flash-based AES key that make Fusion devices the most comprehensive programmable logic device security solution available today. Fusion devices with

AES-based security provide a high level of protection for remote field updates over public networks, such as the Internet, and are designed to ensure that valuable IP remains out of the hands of system overbuilders, system cloners, and IP thieves. As an additional security measure, the FPGA configuration data of a programmed Fusion device cannot be read back, although secure design verification is possible. During design, the user controls and defines both internal and external access to the flash memory blocks.

Security, built into the FPGA fabric, is an inherent component of the Fusion family. The flash cells are located beneath seven metal layers, and many device design and layout techniques have been used to make invasive attacks extremely difficult. Fusion with FlashLock and AES security is unique in being highly resistant to both invasive and noninvasive attacks. Your valuable IP is protected with

industry-standard security, making remote ISP possible. A Fusion device provides the best available security for programmable logic designs.

# Single Chip

Flash-based FPGAs store their configuration information in on-chip flash cells. Once programmed, the configuration data is an inherent part of the FPGA structure, and no external configuration data needs to be loaded at system power-up (unlike SRAM-based FPGAs). Therefore, flash-based Fusion FPGAs do not require system configuration components such as EEPROMs or microcontrollers to load device configuration data. This reduces bill-of-materials costs and PCB area, and increases security and system reliability.



Fusion Device Family Overview

The FlashPoint tool in the Fusion development software solutions, Libero SoC and Designer, has extensive support for flash memory blocks and FlashROM. One such feature is auto-generation of sequential programming files for applications requiring a unique serial number in each part. Another feature allows the inclusion of static data for system version control. Data for the FlashROM can be generated quickly and easily using the Libero SoC and Designer software tools. Comprehensive programming file support is also included to allow for easy programming of large numbers of parts with differing FlashROM contents.

## SRAM and FIFO

Fusion devices have embedded SRAM blocks along the north and south sides of the device. Each variable-aspect-ratio SRAM block is 4,608 bits in size. Available memory configurations are 256×18, 512×9, 1k×4, 2k×2, and 4k×1 bits. The individual blocks have independent read and write ports that can be configured with different bit widths on each port. For example, data can be written through a 4-bit port and read as a single bitstream. The SRAM blocks can be initialized from the flash memory blocks or via the device JTAG port (ROM emulation mode), using the UJTAG macro.

In addition, every SRAM block has an embedded FIFO control unit. The control unit allows the SRAM block to be configured as a synchronous FIFO without using additional core VersaTiles. The FIFO width and depth are programmable. The FIFO also features programmable Almost Empty (AEMPTY) and Almost Full (AFULL) flags in addition to the normal EMPTY and FULL flags. The embedded FIFO control unit contains the counters necessary for the generation of the read and write address pointers. The SRAM/FIFO blocks can be cascaded to create larger configurations.

# **Clock Resources**

# PLLs and Clock Conditioning Circuits (CCCs)

Fusion devices provide designers with very flexible clock conditioning capabilities. Each member of the Fusion family contains six CCCs. In the two larger family members, two of these CCCs also include a PLL; the smaller devices support one PLL.

The inputs of the CCC blocks are accessible from the FPGA core or from one of several inputs with dedicated CCC block connections.

The CCC block has the following key features:

- Wide input frequency range (f<sub>IN CCC</sub>) = 1.5 MHz to 350 MHz
- Output frequency range ( $f_{OUT CCC}$ ) = 0.75 MHz to 350 MHz
- Clock phase adjustment via programmable and fixed delays from -6.275 ns to +8.75 ns
- Clock skew minimization (PLL)
- Clock frequency synthesis (PLL)
- · On-chip analog clocking resources usable as inputs:
  - 100 MHz on-chip RC oscillator
  - Crystal oscillator

Additional CCC specifications:

- Internal phase shift = 0°, 90°, 180°, and 270°
- Output duty cycle =  $50\% \pm 1.5\%$
- Low output jitter. Samples of peak-to-peak period jitter when a single global network is used:
  - 70 ps at 350 MHz
  - 90 ps at 100 MHz
  - 180 ps at 24 MHz
  - Worst case < 2.5% × clock period
- Maximum acquisition time = 150 µs
- Low power consumption of 5 mW

# **Related Documents**

# Datasheet

Core8051 www.microsemi.com/soc/ipdocs/Core8051\_DS.pdf

# **Application Notes**

 Fusion FlashROM

 http://www.microsemi.com/soc/documents/Fusion\_FROM\_AN.pdf

 Fusion SRAM/FIFO Blocks

 http://www.microsemi.com/soc/documents/Fusion\_RAM\_FIFO\_AN.pdf

 Using DDR in Fusion Devices

 http://www.microsemi.com/index.php?option=com\_docman&task=doc\_download&gid=129938

 Fusion Security

 http://www.microsemi.com/soc/documents/Fusion\_Security\_AN.pdf

 Using Fusion RAM as Multipliers

 http://www.microsemi.com/index.php?option=com\_docman&task=doc\_download&gid=129940

# Handbook

Cortex-M1 Handbook www.microsemi.com/soc/documents/CortexM1\_HB.pdf

# **User Guides**

Designer User Guide http://www.microsemi.com/soc/documents/designer\_UG.pdf Fusion FPGA Fabric User Guide http://www.microsemi.com/index.php?option=com\_docman&task=doc\_download&gid=130817 IGLOO, ProASIC3, SmartFusion and Fusion Macro Library Guide http://www.microsemi.com/soc/documents/pa3\_libguide\_ug.pdf SmartGen, FlashROM, Flash Memory System Builder, and Analog System Builder User Guide http://www.microsemi.com/soc/documents/genguide\_ug.pdf

# **White Papers**

Fusion Technology http://www.microsemi.com/soc/documents/Fusion\_Tech\_WP.pdf



# 2 – Device Architecture

# **Fusion Stack Architecture**

To manage the unprecedented level of integration in Fusion devices, Microsemi developed the Fusion technology stack (Figure 2-1). This layered model offers a flexible design environment, enabling design at very high and very low levels of abstraction. Fusion peripherals include hard analog IP and hard and soft digital IP. Peripherals communicate across the FPGA fabric via a layer of soft gates—the Fusion backbone. Much more than a common bus interface, this Fusion backbone integrates a micro-sequencer within the FPGA fabric and configures the individual peripherals and supports low-level processing of peripheral data. Fusion applets are application building blocks that can control and respond to peripherals and other system signals. Applets can be rapidly combined to create large applications. The technology is scalable across devices, families, design types, and user expertise, and supports a well-defined interface for external IP and tool integration.

At the lowest level, Level 0, are Fusion peripherals. These are configurable functional blocks that can be hardwired structures such as a PLL or analog input channel, or soft (FPGA gate) blocks such as a UART or two-wire serial interface. The Fusion peripherals are configurable and support a standard interface to facilitate communication and implementation.

Connecting and controlling access to the peripherals is the Fusion backbone, Level 1. The backbone is a soft-gate structure, scalable to any number of peripherals. The backbone is a bus and much more; it manages peripheral configuration to ensure proper operation. Leveraging the common peripheral interface and a low-level state machine, the backbone efficiently offloads peripheral management from the system design. The backbone can set and clear flags based upon peripheral behavior and can define performance criteria. The flexibility of the stack enables a designer to configure the silicon, directly bypassing the backbone if that level of control is desired.

One step up from the backbone is the Fusion applet, Level 2. The applet is an application building block that implements a specific function in FPGA gates. It can react to stimuli and board-level events coming through the backbone or from other sources, and responds to these stimuli by accessing and manipulating peripherals via the backbone or initiating some other action. An applet controls or responds to the peripheral(s). Applets can be easily imported or exported from the design environment. The applet structure is open and well-defined, enabling users to import applets from Microsemi, system developers, third parties, and user groups.



Note: Levels 1, 2, and 3 are implemented in FPGA logic gates.

Figure 2-1 • Fusion Architecture Stack



Device Architecture

#### Table 2-16 • RTC Control/Status Register

Bit	Name	Description	Default Value
7	rtc_rst	RTC Reset	
		1 – Resets the RTC	
		0 – Deassert reset on after two ACM_CLK cycle.	
6	cntr_en	Counter Enable	0
		1 – Enables the counter; rtc_rst must be deasserted as well. First counter increments after 64 RTCCLK positive edges.	
		0 – Disables the crystal prescaler but does not reset the counter value. Counter value can only be updated when the counter is disabled.	
5	vr_en_mat	Voltage Regulator Enable on Match	0
		1 – Enables RTCMATCH and RTCPSMMATCH to output 1 when the counter value equals the Match Register value. This enables the 1.5 V voltage regulator when RTCPSMMATCH connects to the RTCPSMMATCH signal in VRPSM.	
		0 – RTCMATCH and RTCPSMMATCH output 0 at all times.	
4:3	xt_mode[1:0]	Crystal Mode	00
		Controls RTCXTLMODE[1:0]. Connects to RTC_MODE signal in XTLOSC. XTL_MODE uses this value when xtal_en is 1. See the "Crystal Oscillator" section on page 2-20 for mode configuration.	
2	rst_cnt_omat	Reset Counter on Match	0
		1 – Enables the sync clear of the counter when the counter value equals the Match Register value. The counter clears on the rising edge of the clock. If all the Match Registers are set to 0, the clear is disabled.	
		0 – Counter increments indefinitely	
1	rstb_cnt	Counter Reset, active Low	0
		0 - Resets the 40-bit counter value	
0	xtal_en	Crystal Enable	0
		Controls RTCXTLSEL. Connects to SELMODE signal in XTLOSC.	
		0 – XTLOSC enables control by FPGA_EN; xt_mode is not used. Sleep mode requires this bit to equal 0.	
		1 – Enables XTLOSC, XTL_MODE control by xt_mode	
		Standby mode requires this bit to be set to 1.	
		See the "Crystal Oscillator" section on page 2-20 for further details on SELMODE configuration.	

Table 2-36 describes each pin in the Analog Block. Each function within the Analog Block will be explained in detail in the following sections.

Table 2-36 • Analog Block Pin Description

Signal Name	Number of Bits	Direction	Function	Location of Details
VAREF	1	Input/Output	Voltage reference for ADC	ADC
ADCGNDREF	1	Input	External ground reference	ADC
MODE[3:0]	4	Input	ADC operating mode	ADC
SYSCLK	1	Input	External system clock	
TVC[7:0]	8	Input	Clock divide control	ADC
STC[7:0]	8	Input	Sample time control	ADC
ADCSTART	1	Input	Start of conversion	ADC
PWRDWN	1	Input	ADC comparator power-down if 1. When asserted, the ADC will stop functioning, and the digital portion of the analog block will continue operating. This may result in invalid status flags from the analog block. Therefore, Microsemi does not recommend asserting the PWRDWN pin.	ADC
ADCRESET	1	Input	ADC resets and disables Analog Quad – active high	ADC
BUSY	1	Output	1 – Running conversion	ADC
CALIBRATE	1	Output	1 – Power-up calibration	ADC
DATAVALID	1	Output	1 – Valid conversion result	ADC
RESULT[11:0]	12	Output	Conversion result	ADC
TMSTBINT	1	Input	Internal temp. monitor strobe	ADC
SAMPLE	1	Output	<ul> <li>1 – An analog signal is actively being sampled (stays high during signal acquisition only)</li> <li>0 – No analog signal is being sampled</li> </ul>	ADC
VAREFSEL	1	Input	0 = Output internal voltage reference (2.56 V) to VAREF 1 = Input external voltage reference	ADC
	_		from VAREF and ADCGNDREF	
CHNUMBER[4:0]	5	Input	Analog input channel select	Input multiplexer
ACMCLK	1	Input	ACM clock	ACM
ACMWEN	1	Input	ACM write enable – active high	ACM
ACMRESET	1	Input	ACM reset – active low	ACM
ACMWDATA[7:0]	8	Input	ACM write data	ACM
ACMRDATA[7:0]	8	Output	ACM read data	ACM
ACMADDR[7:0]	8	Input	ACM address	ACM
CMSTB0 to CMSTB9	10	Input	Current monitor strobe – 1 per quad, active high	Analog Quad

# **Current Monitor**

The Fusion Analog Quad is an excellent element for voltage- and current-monitoring applications. In addition to supporting the same functionality offered by the AV pad, the AC pad can be configured to monitor current across an external sense resistor (Figure 2-70). To support this current monitor function, a differential amplifier with 10x gain passes the amplified voltage drop between the AV and AC pads to the ADC. The amplifier enables the user to use very small resistor values, thereby limiting any impact on the circuit. This function of the AC pad does not limit AV pad operation. The AV pad can still be configured for use as a direct voltage input or scaled through the AV prescaler independently of it's use as an input to the AC pad's differential amplifier.



Figure 2-70 • Analog Quad Current Monitor Configuration



#### Figure 2-72 • Positive Current Monitor

Care must be taken when choosing the right resistor for current measurement application. Note that because of the 10× amplification, the maximum measurable difference between the AV and AC pads is  $V_{AREF}$  / 10. A larger AV-to-AC voltage drop will result in ADC saturation; that is, the digital code put out by the ADC will stay fixed at the full scale value. Therefore, the user must select the external sense resistor appropriately. Table 2-38 shows recommended resistor values for different current measurement ranges. When choosing resistor values for a system, there is a trade-off between measurement accuracy and power consumption. Choosing a large resistor will increase the voltage drop and hence increase accuracy of the measurement; however the larger voltage drop dissipates more power (P = I<sup>2</sup> × R).

The Current Monitor is a unipolar system, meaning that the differential voltage swing must be from 0 V to  $V_{AREF}/10$ . Therefore, the Current Monitor only supports differential voltage where  $|V_{AV}-V_{AC}|$  is greater than 0 V. This results in the requirement that the potential of the AV pad must be larger than the potential of the AC pad. This is straightforward for positive voltage systems. For a negative voltage system, it means that the AV pad must be "more negative" than the AC pad. This is shown in Figure 2-73.

In this case, both the AV pad and the AC pad are configured for negative operations and the output of the differential amplifier still falls between 0 V and  $V_{AREF}$  as required.

Current Range	Recommended Minimum Resistor Value (Ohms)
> 5 mA – 10 mA	10 – 20
> 10 mA – 20 mA	5 – 10
> 20 mA – 50 mA	2.5 – 5
> 50 mA – 100 mA	1 – 2
> 100 mA – 200 mA	0.5 – 1
> 200 mA – 500 mA	0.3 – 0.5
> 500 mA – 1 A	0.1 – 0.2
> 1 A – 2 A	0.05 – 0.1
> 2 A – 4 A	0.025 – 0.05
> 4 A – 8 A	0.0125 – 0.025
> 8 A – 12 A	0.00625 – 0.02

Table 2-37 • Recommended Resistor for Different Current Range Measurement

#### Intra-Conversion

Performing a conversion during power-up calibration is possible but should be avoided, since the performance is not guaranteed, as shown in Table 2-49 on page 2-117. This is described as intra-conversion. Figure 2-92 on page 2-113 shows intra-conversion, (conversion that starts during power-up calibration).

#### **Injected Conversion**

A conversion can be interrupted by another conversion. Before the current conversion is finished, a second conversion can be started by issuing a pulse on signal ADCSTART. When a second conversion is issued before the current conversion is completed, the current conversion would be dropped and the ADC would start the second conversion on the rising edge of the SYSCLK. This is known as injected conversion. Since the ADC is synchronous, the minimum time to issue a second conversion is two clock cycles of SYSCLK after the previous one. Figure 2-93 on page 2-113 shows injected conversion, (conversion that starts before a previously started conversion is finished). The total time for calibration still remains 3,840 ADCCLK cycles.

## ADC Example

This example shows how to choose the correct settings to achieve the fastest sample time in 10-bit mode for a system that runs at 66 MHz. Assume the acquisition times defined in Table 2-44 on page 2-108 for 10-bit mode, which gives 0.549 µs as a minimum hold time.

The period of SYSCLK:  $t_{SYSCLK} = 1/66$  MHz = 0.015  $\mu$ s

Choosing TVC between 1 and 33 will meet the maximum and minimum period for the ADCCLK requirement. A higher TVC leads to a higher ADCCLK period.

The minimum TVC is chosen so that  $t_{distrib}$  and  $t_{post-cal}$  can be run faster. The period of ADCCLK with a TVC of 1 can be computed by EQ 24.

$$t_{ADCCLK} = 4 \times (1 + TVC) \times t_{SYSCLK} = 4 \times (1 + 1) \times 0.015 \ \mu s = 0.12 \ \mu s$$

EQ 24

The STC value can now be computed by using the minimum sample/hold time from Table 2-44 on page 2-108, as shown in EQ 25.

STC = 
$$\frac{t_{sample}}{t_{ADCCLK}} - 2 = \frac{0.549 \ \mu s}{0.12 \ \mu s} - 2 = 4.575 - 2 = 2.575$$

EQ 25

You must round up to 3 to accommodate the minimum sample time requirement. The actual sample time,  $t_{sample}$ , with an STC of 3, is now equal to 0.6  $\mu$ s, as shown in EQ 26

$$t_{sample} = (2 + STC) \times t_{ADCCLK} = (2 + 3) \times t_{ADCCLK} = 5 \times 0.12 \ \mu s = 0.6 \ \mu s$$

EQ 26

Microsemi recommends post-calibration for temperature drift over time, so post-calibration is enabled. The post-calibration time,  $t_{post-cal}$ , can be computed by EQ 27. The post-calibration time is 0.24 µs.

$$t_{post-cal} = 2 \times t_{ADCCLK} = 0.24 \ \mu s$$

EQ 27

The distribution time,  $t_{distrib}$ , is equal to 1.2 µs and can be computed as shown in EQ 28 (N is number of bits, referring back to EQ 8 on page 2-94).

$$_{\text{distrib}} = N \times t_{\text{ADCCLK}} = 10 \times 0.12 = 1.2 \, \mu \text{s}$$

t

EQ 28

The total conversion time can now be summated, as shown in EQ 29 (referring to EQ 23 on page 2-109).

 $t_{sync\_read} + t_{sample} + t_{distrib} + t_{post-cal} + t_{sync\_write} = (0.015 + 0.60 + 1.2 + 0.24 + 0.015) \ \mu s = 2.07 \ \mu s = EQ \ 29$ 



**Analog System Characteristics** 

#### Table 2-49 • Analog Channel Specifications

#### Commercial Temperature Range Conditions, T<sub>J</sub> = 85°C (unless noted otherwise), Typical: VCC33A = 3.3 V, VCC = 1.5 V

Parameter	Description	Condition	Min.	Тур.	Max.	Units
Voltage Monitor	Using Analog Pads AV,	AC and AT (using prescaler)			l	
	Input Voltage (Prescaler)	Refer to Table 3-2 on page 3-3				
VINAP	Uncalibrated Gain and Offset Errors	Refer to Table 2-51 on page 2-122				
	Calibrated Gain and Offset Errors	Refer to Table 2-52 on page 2-123				
	Bandwidth1				100	KHz
	Input Resistance	Refer to Table 3-3 on page 3-4				
	Scaling Factor	Prescaler modes (Table 2-57 on page 2-130)				
	Sample Time		10			μs
<b>Current Monitor</b>	Using Analog Pads AV	and AC		•		
VRSM <sup>1</sup>	Maximum Differential Input Voltage				VAREF / 10	mV
	Resolution	Refer to "Current Monitor" section				
	Common Mode Range				- 10.5 to +12	V
CMRR	Common Mode Rejection Ratio	DC – 1 KHz		60		dB
		1 KHz - 10 KHz		50		dB
		> 10 KHz		30		dB
t <sub>CMSHI</sub>	Strobe High time		ADC conv. time		200	μs
t <sub>CMSHI</sub>	Strobe Low time		5			μs
t <sub>CMSHI</sub>	Settling time		0.02			μs
	Accuracy	Input differential voltage > 50 mV			-2 -(0.05 x VRSM) to +2 + (0.05 x VRSM)	mV

Notes:

1. VRSM is the maximum voltage drop across the current sense resistor.

2. Analog inputs used as digital inputs can tolerate the same voltage limits as the corresponding analog pad. There is no reliability concern on digital inputs as long as VIND does not exceed these limits.

- 3. VIND is limited to VCC33A + 0.2 to allow reaching 10 MHz input frequency.
- 4. An averaging of 1,024 samples (LPF setting in Analog System Builder) is required and the maximum capacitance allowed across the AT pins is 500 pF.
- 5. The temperature offset is a fixed positive value.
- 6. The high current mode has a maximum power limit of 20 mW. Appropriate current limit resistors must be used, based on voltage on the pad.
- 7. When using SmartGen Analog System Builder, CalibIP is required to obtain specified offset. For further details on CalibIP, refer to the "Temperature, Voltage, and Current Calibration in Fusion FPGAs" chapter of the Fusion FPGA Fabric User Guide.

# **I/O Registers**

Each I/O module contains several input, output, and enable registers. Refer to Figure 2-100 for a simplified representation of the I/O block.

The number of input registers is selected by a set of switches (not shown in Figure 2-100) between registers to implement single or differential data transmission to and from the FPGA core. The Designer software sets these switches for the user.

A common CLR/PRE signal is employed by all I/O registers when I/O register combining is used. Input register 2 does not have a CLR/PRE pin, as this register is used for DDR implementation. The I/O register combining must satisfy some rules.



Note: Fusion I/Os have registers to support DDR functionality (see the "Double Data Rate (DDR) Support" section on page 2-139 for more information).

Figure 2-100 • I/O Block Logical Representation

## Table 2-78 • Fusion Standard I/O Standards—OUT\_DRIVE Settings

		OUT_DRIVE (mA)								
I/O Standards	2	4	6	8	Slew					
LVTTL/LVCMOS 3.3 V	3	3	3	3	High	Low				
LVCMOS 2.5 V	3	3	3	3	High	Low				
LVCMOS 1.8 V	3	3	-	-	High	Low				
LVCMOS 1.5 V	3	_	-	-	High	Low				

## Table 2-79 • Fusion Advanced I/O Standards—SLEW and OUT\_DRIVE Settings

		OUT_DRIVE (mA)									
I/O Standards	2	4	6	8	12	16	Slew				
LVTTL/LVCMOS 3.3 V	3	3	3	3	3	3	High	Low			
LVCMOS 2.5 V	3	3	3	3	3	-	High Low				
LVCMOS 1.8 V	3	3	3	3	-	-	High	Low			
LVCMOS 1.5 V	3	3	_	_	_	_	High	Low			

Table 2-80	<ul> <li>Fusion Pro</li> </ul>	I/O Standards-	-SLEW and OUT	DRIVE Settings
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I/O Standards	2	4	6	8	12	16	24	Slew		
LVTTL/LVCMOS 3.3 V	3	3	3	3	3	3	3	High	Low	
LVCMOS 2.5 V	3	3	3	3	3	3	3	High	Low	
LVCMOS 2.5 V/5.0 V	3	3	3	3	3	3	3	High	Low	
LVCMOS 1.8 V	3	3	3	3	3	3	-	High	Low	
LVCMOS 1.5 V	3	3	3	3	3	_	_	High	Low	





Figure 2-114 • Naming Conventions of Fusion Devices with Four I/O Banks





*Figure 2-116* • Input Buffer Timing Model and Delays (example)



Input Low (V)	Input High (V)	Measuring Point* (V)	VREF (typ.) (V)	C <sub>LOAD</sub> (pF)
0	3.3	1.4	-	35

Note: \*Measuring point = Vtrip. See Table 2-90 on page 2-166 for a complete table of trip points.

#### Timing Characteristics

## Table 2-104 • 3.3 V LVTTL / 3.3 V LVCMOS Low Slew

Commercial Temperature Range Conditions: T<sub>J</sub> = 70°C, Worst-Case VCC = 1.425 V, Worst-Case VCCI = 3.0 V Applicable to Pro I/Os

Drive Strength	Speed Grade	t <sub>DOUT</sub>	t <sub>DP</sub>	t <sub>DIN</sub>	t <sub>PY</sub>	t <sub>PYS</sub>	t <sub>EOUT</sub>	t <sub>ZL</sub>	t <sub>zH</sub>	t <sub>LZ</sub>	t <sub>HZ</sub>	t <sub>zLS</sub>	t <sub>zHS</sub>	Units
4 mA	Std.	0.66	11.01	0.04	1.20	1.57	0.43	11.21	9.05	2.69	2.44	13.45	11.29	ns
	-1	0.56	9.36	0.04	1.02	1.33	0.36	9.54	7.70	2.29	2.08	11.44	9.60	ns
	-2	0.49	8.22	0.03	0.90	1.17	0.32	8.37	6.76	2.01	1.82	10.04	8.43	ns
8 mA	Std.	0.66	7.86	0.04	1.20	1.57	0.43	8.01	6.44	3.04	3.06	10.24	8.68	ns
	-1	0.56	6.69	0.04	1.02	1.33	0.36	6.81	5.48	2.58	2.61	8.71	7.38	ns
	-2	0.49	5.87	0.03	0.90	1.17	0.32	5.98	4.81	2.27	2.29	7.65	6.48	ns
12 mA	Std.	0.66	6.03	0.04	1.20	1.57	0.43	6.14	5.02	3.28	3.47	8.37	7.26	ns
	-1	0.56	5.13	0.04	1.02	1.33	0.36	5.22	4.27	2.79	2.95	7.12	6.17	ns
	-2	0.49	4.50	0.03	0.90	1.17	0.32	4.58	3.75	2.45	2.59	6.25	5.42	ns
16 mA	Std.	0.66	5.62	0.04	1.20	1.57	0.43	5.72	4.72	3.32	3.58	7.96	6.96	ns
	-1	0.56	4.78	0.04	1.02	1.33	0.36	4.87	4.02	2.83	3.04	6.77	5.92	ns
	-2	0.49	4.20	0.03	0.90	1.17	0.32	4.27	3.53	2.48	2.67	5.94	5.20	ns
24 mA	Std.	0.66	5.24	0.04	1.20	1.57	0.43	5.34	4.69	3.39	3.96	7.58	6.93	ns
	-1	0.56	4.46	0.04	1.02	1.33	0.36	4.54	3.99	2.88	3.37	6.44	5.89	ns
	-2	0.49	3.92	0.03	0.90	1.17	0.32	3.99	3.50	2.53	2.96	5.66	5.17	ns

Note: For the derating values at specific junction temperature and voltage supply levels, refer to Table 3-7 on page 3-9.





Figure	2-145 •	<b>Output DDR</b>	Timing	Diagram

**Timing Characteristics** 

Table 2-182 • Output DDR Propagation Delays	
Commercial Temperature Range Conditions: T <sub>1</sub> = 70°C, Worst-Case VCC = 1.425 V	

Parameter	Description	-2	-1	Std.	Units
t <sub>DDROCLKQ</sub>	Clock-to-Out of DDR for Output DDR	0.70	0.80	0.94	ns
t <sub>DDROSUD1</sub>	Data_F Data Setup for Output DDR	0.38	0.43	0.51	ns
t <sub>DDROSUD2</sub>	Data_R Data Setup for Output DDR	0.38	0.43	0.51	ns
t <sub>DDROHD1</sub>	Data_F Data Hold for Output DDR	0.00	0.00	0.00	ns
t <sub>DDROHD2</sub>	Data_R Data Hold for Output DDR	0.00	0.00	0.00	ns
t <sub>DDROCLR2Q</sub>	Asynchronous Clear-to-Out for Output DDR	0.80	0.91	1.07	ns
t <sub>DDROREMCLR</sub>	Asynchronous Clear Removal Time for Output DDR	0.00	0.00	0.00	ns
t <sub>DDRORECCLR</sub>	Asynchronous Clear Recovery Time for Output DDR	0.22	0.25	0.30	ns
t <sub>DDROWCLR1</sub>	Asynchronous Clear Minimum Pulse Width for Output DDR	0.22	0.25	0.30	ns
t <sub>DDROCKMPWH</sub>	Clock Minimum Pulse Width High for the Output DDR	0.36	0.41	0.48	ns
t <sub>DDROCKMPWL</sub>	Clock Minimum Pulse Width Low for the Output DDR	0.32	0.37	0.43	ns
F <sub>DDOMAX</sub>	Maximum Frequency for the Output DDR	1404	1232	1048	MHz

Note: For the derating values at specific junction temperature and voltage supply levels, refer to Table 3-7 on page 3-9.



The 1.76 W power is less than the required 3.00 W. The design therefore requires a heat sink, or the airflow where the device is mounted should be increased. The design's total junction-to-air thermal resistance requirement can be estimated by EQ 7:

$$\theta_{ja(total)} = \frac{T_J - T_A}{P} = \frac{100^{\circ}C - 70^{\circ}C}{3.00 W} = 10.00^{\circ}C/W$$

Determining the heat sink's thermal performance proceeds as follows:

$$\theta_{\text{JA(TOTAL)}} = \theta_{\text{JC}} + \theta_{\text{CS}} + \theta_{\text{SA}}$$

EQ 8

EQ 7

where

- $\theta_{JA} = 0.37^{\circ}C/W$ 
  - Thermal resistance of the interface material between the case and the heat sink, usually provided by the thermal interface manufacturer

 $\theta_{SA}$  = Thermal resistance of the heat sink in °C/W

$$\theta_{SA} = \theta_{JA(TOTAL)} - \theta_{JC} - \theta_{CS}$$

EQ 9

$$\theta_{SA} = 13.33^{\circ}C/W - 8.28^{\circ}C/W - 0.37^{\circ}C/W = 5.01^{\circ}C/W$$

A heat sink with a thermal resistance of 5.01°C/W or better should be used. Thermal resistance of heat sinks is a function of airflow. The heat sink performance can be significantly improved with increased airflow.

Carefully estimating thermal resistance is important in the long-term reliability of an Microsemi FPGA. Design engineers should always correlate the power consumption of the device with the maximum allowable power dissipation of the package selected for that device.

Note: The junction-to-air and junction-to-board thermal resistances are based on JEDEC standard (JESD-51) and assumptions made in building the model. It may not be realized in actual application and therefore should be used with a degree of caution. Junction-to-case thermal resistance assumes that all power is dissipated through the case.

## Temperature and Voltage Derating Factors

Table 3-7 • Temperature and Voltage Derating Factors for Timing Delays<br/>(normalized to  $T_J = 70^{\circ}$ C, Worst-Case VCC = 1.425 V)

Array Voltage VCC (V)	Junction Temperature (°C)						
	–40°C	0°C	25°C	70°C	85°C	100°C	
1.425	0.88	0.93	0.95	1.00	1.02	1.05	
1.500	0.83	0.88	0.90	0.95	0.96	0.99	
1.575	0.80	0.85	0.87	0.91	0.93	0.96	

Parameter	Description	Conditions	Temp.	Min	Тур	Мах	Unit
ICC <sup>1</sup>	1.5 V quiescent current	Operational standby <sup>4</sup> , VCC = 1.575 V	T <sub>J</sub> = 25°C		13	25	mA
			T <sub>J</sub> = 85°C		20	45	mA
			T <sub>J</sub> =100°C		25	75	mA
		Standby mode <sup>5</sup> or Sleep mode <sup>6</sup> , VCC = 0 V			0	0	μA
ICC33 <sup>2</sup>	3.3 V analog supplies	Operational standby <sup>4</sup> ,	T <sub>J</sub> = 25°C		9.8	13	mA
	current	VCC33 = 3.63 V	T <sub>J</sub> = 85°C		10.7	14	mA
			T <sub>J</sub> = 100°C		10.8	15	mA
		Operational standby,	T <sub>J</sub> = 25°C		0.31	2	mA
		only Analog Quad and -3.3 v output ON, VCC33 = 3.63 V	T <sub>J</sub> = 85°C		0.35	2	mA
			T <sub>J</sub> = 100°C		0.45	2	mA
		Standby mode <sup>5</sup> , VCC33 = 3.63 V	T <sub>J</sub> = 25°C		2.8	3.6	mA
			T <sub>J</sub> = 85°C		2.9	4	mA
			T <sub>J</sub> = 100°C		3.5	6	mA
		Sleep mode <sup>6</sup> , V <sub>CC33</sub> = 3.63 V	T <sub>J</sub> = 25°C		17	19	μA
			T <sub>J</sub> = 85°C		18	20	μA
			T <sub>J</sub> = 100°C		24	25	μA
ICCI <sup>3</sup>	I/O quiescent current	Operational standby <sup>4</sup> , VCClx = 3.63 V	T <sub>J</sub> = 25°C		417	648	μA
			T <sub>J</sub> = 85°C		417	648	μA
			T <sub>J</sub> = 100°C		417	649	μA
IJTAG	JTAG I/O quiescent current	Operational standby <sup>4</sup> ,	T <sub>J</sub> = 25°C		80	100	μA
		VJTAG = 3.63 V	T <sub>J</sub> = 85°C		80	100	μA
			T <sub>J</sub> = 100°C		80	100	μA
		Standby mode <sup>5</sup> or Sleep mode <sup>6</sup> , VJTAG = 0 V			0	0	μA

Table 3-9 •	AFS600 Quiescent Supply Current Characteristics
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Notes:

1. ICC is the 1.5 V power supplies, ICC and ICC15A.

2. ICC33A includes ICC33A, ICC33PMP, and ICCOSC.

3. ICCI includes all ICCI0, ICCI1, ICCI2, and ICCI4.

4. Operational standby is when the Fusion device is powered up, all blocks are used, no I/O is toggling, Voltage Regulator is loaded with 200 mA, VCC33PMP is ON, XTAL is ON, and ADC is ON.

5. XTAL is configured as high gain, VCC = VJTAG = VPUMP = 0 V.

6. Sleep Mode, VCC = VJTAG = VPUMP = 0 V.



DC and Power Characteristics

Table 3-10 • AFS250 Q	Quiescent Supply Current	Characteristics (continued)
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Parameter	Description	Conditions	Temp.	Min	Тур	Мах	Unit
IPP	Programming supply	Non-programming mode, VPUMP = 3.63 V	T <sub>J</sub> = 25°C		37	80	μA
	current		T <sub>J</sub> = 85°C		37	80	μA
			T <sub>J</sub> = 100°C		80	100	μA
		Standby mode <sup>5</sup> or Sleep mode <sup>6</sup> , VPUMP = 0 V			0	0	μA
ICCNVM	Embedded NVM current	Reset asserted, VCCNVM = 1.575 V	T <sub>J</sub> = 25°C		10	40	μA
			T <sub>J</sub> = 85°C		14	40	μA
			T <sub>J</sub> = 100°C		14	40	μA
ICCPLL	1.5 V PLL quiescent current	Operational standby, VCCPLL = 1.575 V	T <sub>J</sub> = 25°C		65	100	μA
			T <sub>J</sub> = 85°C		65	100	μA
			T <sub>J</sub> = 100°C		65	100	μA

Notes:

- 1. ICC is the 1.5 V power supplies, ICC, ICCPLL, ICC15A, ICCNVM.
- 2. ICC33A includes ICC33A, ICC33PMP, and ICCOSC.
- 3. ICCI includes all ICCI0, ICCI1, and ICCI2.
- 4. Operational standby is when the Fusion device is powered up, all blocks are used, no I/O is toggling, Voltage Regulator is loaded with 200 mA, VCC33PMP is ON, XTAL is ON, and ADC is ON.
- 5. XTAL is configured as high gain, VCC = VJTAG = VPUMP = 0 V.
- 6. Sleep Mode, VCC = VJTA G = VPUMP = 0 V.



# **Datasheet Categories**

## Categories

In order to provide the latest information to designers, some datasheet parameters are published before data has been fully characterized from silicon devices. The data provided for a given device, as highlighted in the "Fusion Device Status" table, is designated as either "Product Brief," "Advance," "Preliminary," or "Production." The definitions of these categories are as follows:

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The product brief is a summarized version of a datasheet (advance or production) and contains general product information. This document gives an overview of specific device and family information.

## Advance

This version contains initial estimated information based on simulation, other products, devices, or speed grades. This information can be used as estimates, but not for production. This label only applies to the DC and Switching Characteristics chapter of the datasheet and will only be used when the data has not been fully characterized.

## Preliminary

The datasheet contains information based on simulation and/or initial characterization. The information is believed to be correct, but changes are possible.

## Production

This version contains information that is considered to be final.

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